

Features

- High Density Cell Desihn for Ultra Low R_{DS(on)}
- · Ultra Low Gate Charge
- · Low Reverse Transfer Capacitance
- · Excellent Package for Good Heat Dissipation
- Fully Characterized Avalanche Voltage and Current
- · Epoxy Meets UL 94 V-0 Flammability Rating
- · Moisture Sensitivity Level 1
- · Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

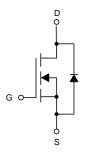
Operating Junction Temperature Range : -55°C to +150°C

• Storage Temperature Range: -55°C to +150°C

• Thermal Resistance: 100°C/W Junction to Ambient

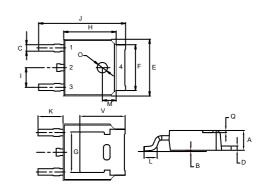
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Volltage	V _{GS}	±20	V
Continuous Drain Current	I _D	40	Α
Pulsed Drain Current	I _{DM}	160	Α
Single Pulse Avalanche Energy	E _{AS}	320	mJ
Total Power Dissipation	P _D	1.25	W

Internal Structure



N-CHANNEL MOSFET





- 1. Gate
- 2,4. Drain
 - 3. Source

DIMENSIONS					
DIM	INCHES		MM		NOTE
DIIVI	MIN	MAX	MIN	MAX	NOTE
Α	0.087	0.094	2.20	2.40	
В	0.000	0.005	0.00	0.13	
С	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
Е	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		TYP.
Η	0.236	0.244	6.00	6.20	
I	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
K	0.114		2.90		TYP.
L	0.055	0.067	1.40	1.70	
М	0.063		1.60		TYP.
0	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.211		5.3	35	TYP.



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

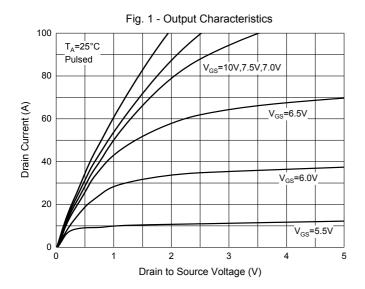
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static Characteristics			•			1
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =250μA	100			V
Gate-Source Leakage Current	I _{GSS}	V_{DS} =0V, V_{GS} =±20V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V, V _{GS} =0V			1	μA
Gate-Threshold Voltage ^(Note 1)	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1		2.5	V
Drain-Source On-Resistance ^(Note 1)	R _{DS(on)}	V _{GS} =10V, I _D =28A		14	17	mΩ
Forward Tranconductance ^(Note 1)	9 FS	V _{DS} =25V, I _D =28A	32			S
Dynamic Characteristics(Note 2)				•		
Input Capacitance	C _{iss}	V _{DS} =30V,V _{GS} =0V,f=1MHz		3400		
Output Capacitance	C _{oss}			290		pF
Reverse Transfer Capacitance	C _{rss}			221		
Total Gate Charge	Q_g			94		nC
Gate-Source Charge	Q_{gs}	$V_{DD} = 30V, V_{GS} = 10V, I_{D} = 30A$		16		
Gate-Drain Charge	Q_{gd}			24		
Turn-On Delay Time	t _{d(on)}			15		
Turn-On Rise Time	t _r	V_{DD} =30V, V_{GS} =10V, R_{G} =2.5 Ω , I_{D} =2A, R_{L} =15 Ω		11		
Turn-Off Delay Time	t _{d(off)}			52		ns
Turn-Off Fall Time	t _f			13		
Drain-Source Body Diode Cha	racteristi	cs		1		l
Continuous Body Diode Current	Is	T _c =25°C			40	^
Pulsed Diode Forward Current	I _{SM}	1 _C =23 U			160	Α
Body Diode Voltage	V _{SD}	I _S =28A, V _{GS} =0V			1.2	V

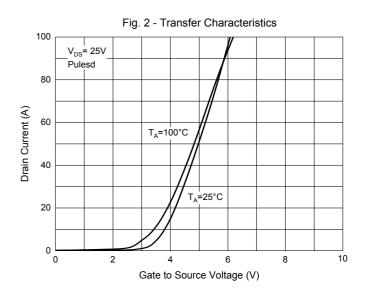
Note 1. Pulse Test : Pulse Width≤300µs, Duty Cycle ≤ 1%.

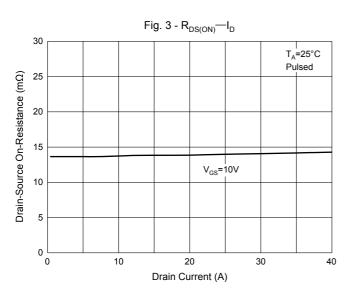
^{2.} Guaranteed by Design, Not Subject to Production Testing.

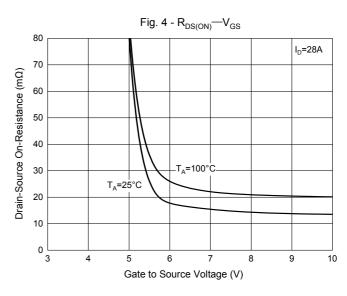


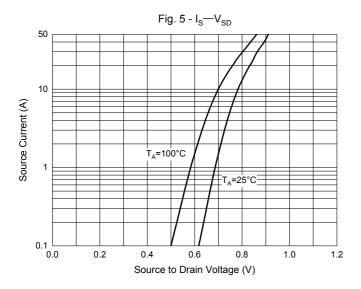
Curve Characteristics

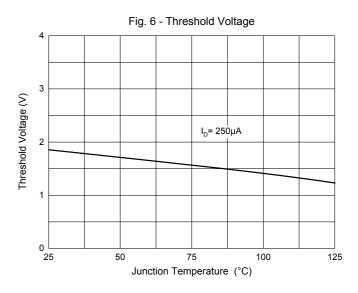














Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel

Note: Adding "-HF" Suffix for Halogen Free, eg. Part Number-TP-HF

IMPORTANT NOTICE

Micro Commercial Components Corp. reserves the right to make changes without further notice to any product herein to make corrections, modifications, enhancements, improvements, or other changes. **Micro Commercial Components Corp**. does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold **Micro Commercial Components Corp**, and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

MCC's products are not authorized for use as critical components in life support devices or systems without the express written approval of Micro Commercial Components Corporation.

CUSTOMER AWARENESS

Counterfeiting of semiconductor parts is a growing problem in the industry. Micro Commercial Components (MCC) is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. MCC strongly encourages customers to purchase MCC parts either directly from MCC or from Authorized MCC Distributors who are listed by country on our web page cited below. Products customers buy either from MCC directly or from Authorized MCC Distributors are genuine parts, have full traceability, meet MCC's quality standards for handling and storage. MCC will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. MCC is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

Rev.3-2-12052019 4/4 MCCSEMI.COM

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by Micro Commercial Components (MCC) manufacturer:

Other Similar products are found below:

614233C 648584F MCH3443-TL-E MCH6422-TL-E FDPF9N50NZ FW216A-TL-2W FW231A-TL-E APT5010JVR NTNS3A92PZT5G IRF100S201 JANTX2N5237 2SK2464-TL-E 2SK3818-DL-E FCA20N60_F109 FDZ595PZ STD6600NT4G FSS804-TL-E 2SJ277-DL-E 2SK1691-DL-E 2SK2545(Q,T) D2294UK 405094E 423220D MCH6646-TL-E TPCC8103,L1Q(CM 367-8430-0972-503 VN1206L 424134F 026935X 051075F SBVS138LT1G 614234A 715780A NTNS3166NZT5G 751625C 873612G IRF7380TRHR IPS70R2K0CEAKMA1 RJK60S3DPP-E0#T2 RJK60S5DPK-M0#T0 APT5010JVFR APT12031JFLL APT12040JVR DMN3404LQ-7 NTE6400 JANTX2N6796U JANTX2N6784U JANTXV2N5416U4 SQM110N05-06L-GE3 SIHF35N60E-GE3